

Reflective/Terminal Type with Visible Light Cut Filter (Standard Sensing Distance = 5 mm)

- Dust resistant structure
- Type with screw mounted tab (M3)



⚠ Be sure to read *Safety Precautions* on Page 3.

RoHS Compliant

Ordering Information

Photomicrosensor

| Appearance | Sensing method | Connecting method | Standard sensing distance | Output type | Model | Minimum packing unit (Unit: pcs) |
|------------|----------------|-----------------------------|---------------------------|-----------------|--------|----------------------------------|
| | Reflective | Terminal for cord soldering | 5 mm | Phototransistor | EE-SB5 | 1 |

Note: Order in multiples of minimum packing unit.

Ratings, Characteristics and Exterior Specifications

Absolute Maximum Ratings (Ta = 25°C)

| Item | Symbol | Rated value | Unit |
|---------------------------|-----------|-------------|------|
| Emitter | | | |
| Forward current | I_F | 50*1 | mA |
| Pulse forward current | I_{FP} | 1*2 | A |
| Reverse voltage | V_R | 4 | V |
| Detector | | | |
| Collector-Emitter voltage | V_{CEO} | 30 | V |
| Emitter-Collector voltage | V_{ECO} | — | V |
| Collector current | I_C | 20 | mA |
| Collector dissipation | P_C | 100*1 | mW |
| Operating temperature | T_{opr} | -25 to 80 | °C |
| Storage temperature | T_{stg} | -30 to 80 | °C |
| Soldering temperature | T_{sol} | 260*3 | °C |

*1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C.

*2. Pulse width $\leq 10 \mu s$, Repeated 100 Hz

*3. Complete soldering within 10 seconds.

Exterior Specifications

| Connecting method | Weight (g) | Material |
|-----------------------------|------------|---------------|
| | | Case |
| Terminal for cord soldering | 1 | Polycarbonate |

Electrical and Optical Characteristics (Ta = 25°C)

| Item | Symbol | Value | | | Unit | Condition |
|--------------------------------------|----------------------|-------|------|------|---------|--|
| | | MIN. | TYP. | MAX. | | |
| Emitter | | | | | | |
| Forward voltage | V_F | — | 1.2 | 1.5 | V | $I_F = 30 \text{ mA}$ |
| Reverse current | I_R | — | 0.01 | 10 | μA | $V_R = 4 \text{ V}$ |
| Peak emission wavelength | λ_P | — | 940 | — | nm | $I_F = 20 \text{ mA}$ |
| Detector | | | | | | |
| Light current | I_L | 200 | — | 2000 | μA | $I_F = 20 \text{ mA}$, $V_{CE} = 10 \text{ V}$ Reflectance 90% White paper $d = 5 \text{ mm}^*$ |
| Dark current | I_D | — | 2 | 200 | nA | $V_{CE} = 10 \text{ V}$, 0 lx |
| Leakage current | I_{LEAK} | — | — | 2 | μA | $I_F = 20 \text{ mA}$, $V_{CE} = 10 \text{ V}$ Non-reflective state |
| Collector-Emitter saturated voltage | $V_{CE}(\text{sat})$ | — | — | — | V | — |
| Peak spectral sensitivity wavelength | λ_P | — | 850 | — | nm | $V_{CE} = 10 \text{ V}$ |
| Rising time | t_r | — | 30 | — | μs | $V_{CC} = 5 \text{ V}$, $R_L = 1 \text{ k}\Omega$ $I_L = 1 \text{ mA}$ |
| Falling time | t_f | — | 30 | — | μs | $V_{CC} = 5 \text{ V}$, $R_L = 1 \text{ k}\Omega$ $I_L = 1 \text{ mA}$ |

* "d" is the distance from the top of the sensor to the reflective surface

Engineering Data (Reference Value)

Fig 1. Forward Current vs. Collector Dissipation Temperature Rating

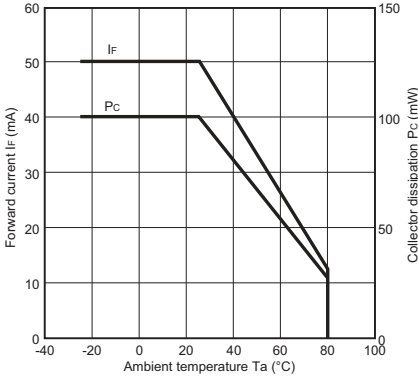


Fig 2. Light Current vs. Forward Current Characteristics (Typical)

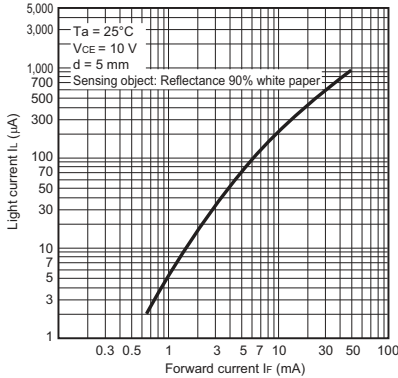


Fig 3. Light Current vs. Collector-Emitter Voltage Characteristics (Typical)

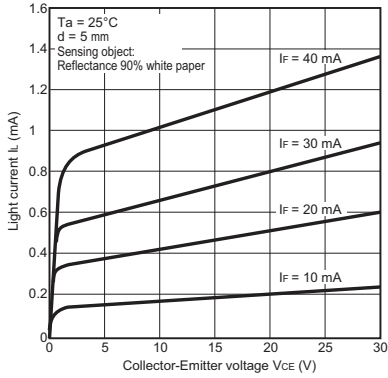


Fig 4. Relative Light Current vs. Ambient Temperature Characteristics (Typical)

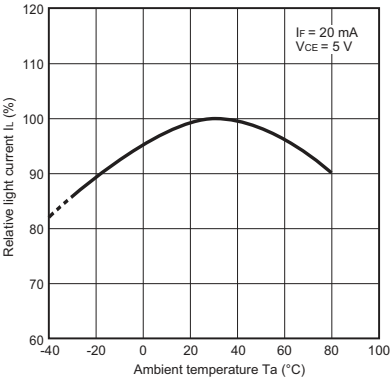


Fig 5. Dark Current vs. Ambient Temperature Characteristics (Typical)

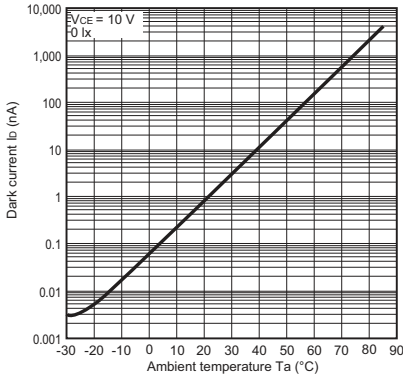


Fig 6. Response Time vs. Load Resistance Characteristics (Typical)

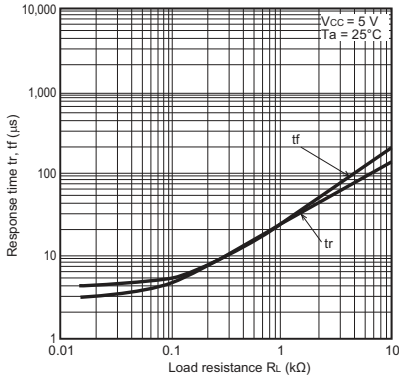


Fig 7. Sensing Distance Characteristics (Typical)

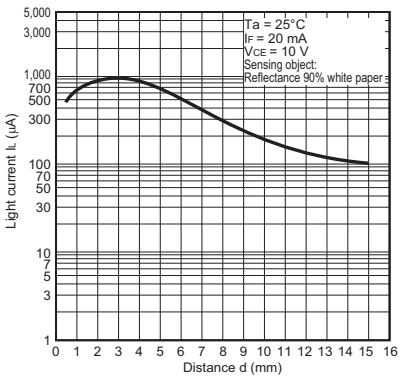


Fig 8. Sensing Position Characteristics (Typical)

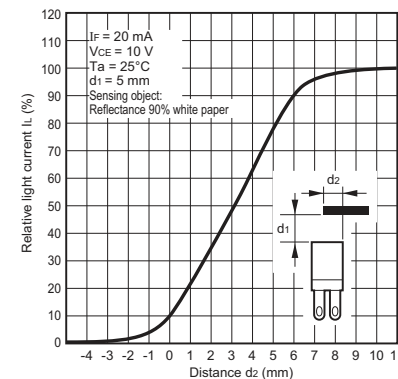


Fig 9. Sensing Position Characteristics (Typical)

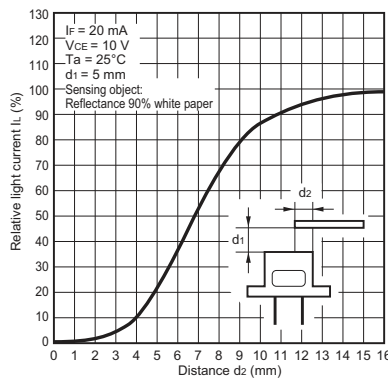


Fig 10. Sensing Angle Characteristics (Typical)

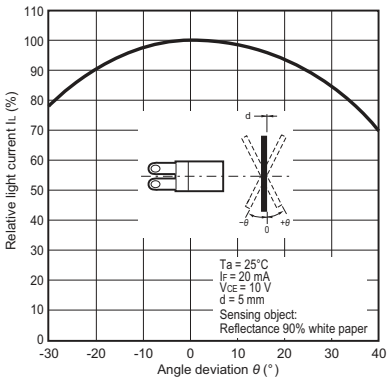
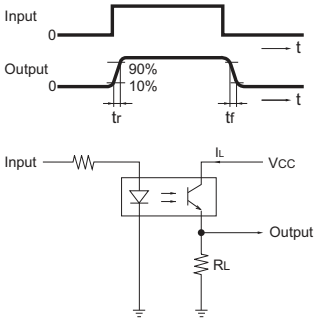


Fig 11. Response Time Measurement Circuit



Safety Precautions

To ensure safe operation, be sure to read and follow the Instruction Manual provided with the Sensor.

⚠ CAUTION

This product is not designed or rated for ensuring safety of persons either directly or indirectly. Do not use it for such purposes.

Precautions for Correct Use

Do not use the product in atmospheres or environments that exceed product ratings.

Precautions for Safe Use

Do not use the product with a voltage or current that exceeds the rated range.
Applying a voltage or current that is higher than the rated range may result in explosion or fire.

Do not miswire such as the polarity of the power supply voltage.
Otherwise the product may be damaged or it may burn.

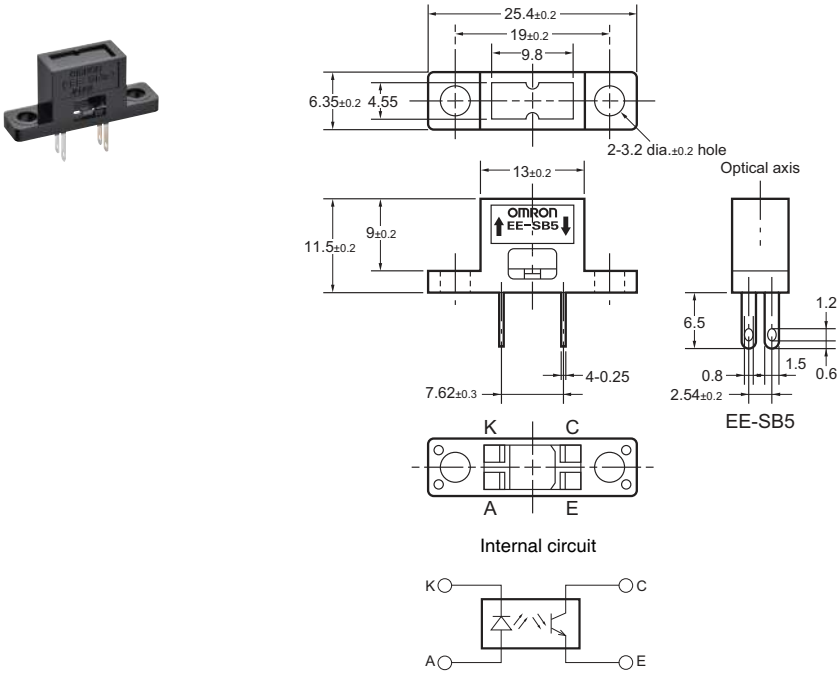
This product does not resist water. Do not use the product in places where water or oil may be sprayed onto the product.

Dimensions and Internal Circuit

(Unit: mm)

Photomicrosensor

EE-SB5



Unless otherwise specified, the tolerances are as shown below.

| Dimensions | Tolerance |
|--------------|-----------|
| 3 mm max. | ±0.3 |
| 3 < mm ≤ 6 | ±0.375 |
| 6 < mm ≤ 10 | ±0.45 |
| 10 < mm ≤ 18 | ±0.55 |
| 18 < mm ≤ 30 | ±0.65 |

| Terminal No. | Name |
|--------------|-----------|
| A | Anode |
| K | Cathode |
| C | Collector |
| E | Emitter |

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